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PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
09/588,419	06/06/2000	Joseph C. Olson	V0077/7124WRM	9440	
75	90 05/07/2003				
Gary L Loser Esq  Vice President and General Counsel  Varian Semiconductor Equipment Associates Inc			EXAMINER		
			DAVID A		
35 Dory Road	01020		ART UNIT	ART UNIT PAPER NUMBER	
Gloucester, MA	01930	•	2881		
			DATE MAILED: 05/07/2003		

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	- UP				
Office Avril 0	09/588,419	OLSON ET AL.					
Office Action Summary	Examiner	Art Unit					
	David A Vanore	2881					
r̃he MAILING DATE of this communication app Period for Reply	pears on the cover she t with th	correspondence addre	ss				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a repl If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute  - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).  Status	36(a). In no event, however, may a reply by within the statutory minimum of thirty (30) will apply and will expire SIX (6) MONTHS for cause the application to become ABANCO	e timely filed  days will be considered timely.  rom the mailing date of this comm	nunication.				
1) Responsive to communication(s) filed on 171	<u>March 2003</u> .						
2a)⊠ This action is <b>FINAL</b> . 2b)□ Th	is action is non-final.		•				
3) Since this application is in condition for allows closed in accordance with the practice under	ance except for formal matters, Ex parte Quayle, 1935 C.D. 11	prosecution as to the m	nerits is				
Disposition of Claims							
4)⊠ Claim(s) <u>1-25</u> is/are pending in the application							
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) <u>23</u> is/are allowed.	D)⊠ Claim(s) <u>23</u> is/are allowed.						
6)⊠ Claim(s) <u>1-22,24 and 25</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/o	r election requirement.						
Application Papers							
9) The specification is objected to by the Examine							
10)⊠ The drawing(s) filed on <u>06 June 2000</u> is/are: a)	•	•					
Applicant may not request that any objection to the	•	• • •					
11) The proposed drawing correction filed on		proved by the Examiner.					
If approved, corrected drawings are required in rep	•						
12) The oath or declaration is objected to by the Ex	aminer.						
Priority under 35 U.S.C. §§ 119 and 120							
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119	(a)-(d) or (f).					
a) ☐ All b) ☐ Some * c) ☐ None of:							
1. Certified copies of the priority documents							
<ol><li>Certified copies of the priority documents</li></ol>	2. Certified copies of the priority documents have been received in Application No						
<ul> <li>3. Copies of the certified copies of the prior application from the International But</li> <li>* See the attached detailed Office action for a list</li> </ul>	eau (PCT Rule 17.2(a)).		ge				
14) ☐ Acknowledgment is made of a claim for domestic	·		olication)				
a) The translation of the foreign language pro- 15) Acknowledgment is made of a claim for domesti-	visional application has been re	eceived.	· · · · · · · · · · · · · · · · · · ·				
attachment(s)							
) Notice of References Cited (PTO-892) ) Notice of Draftsperson's Patent Drawing Review (PTO-948) ) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informa	ary (PTO-413) Paper No(s) al Patent Application (PTO-152					

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## Response to Arguments

Applicant's arguments filed in the amendment received on September 17, 2003, have been fully considered but are not persuasive.

Applicant has amended the independent claims to include language indicating that the determination of beam parallelism and direction claimed by the Applicant are performed during an implant process and argues that Smick et al. fails to teach this limitation.

Smick et al. clearly teaches the measurement of beam parallelism and direction using the apparatus and method recited by the Applicant's claims (Col. 10 Lines 18-31) as pointed out in the last Office action, save for claim 23 whose reasons for allowability are noted below.

Claims 1-22 and 24-25 stand finally rejected by Smick et al.

#### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-22 and 24-25 stand rejected under 35 U.S.C. 102(b) as being clearly anticipated by Smick et al.

Smick et al. teaches a device and method for determining the parallelism of a beam comprising the following:

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1) A method and device for forming a charged particle beam (13) for irradiation of semiconductor material as recited in claims 1, 11, 14, 15, and 25.

- 2) A method and device for maintaining scan uniformity comprising forming an adjusted intensity profile at a first position using a slit which blocks a portion of the beam (Fig. 5 Item 70') and detecting the intensity profile, using Faraday detectors, of the beam downstream of the slit (Fig. 5 Item 72) and at a second position (Fig. 5 Item 16) where the parallelism of the beam is determined with respect to a reference direction (Col 8 Lines 10-68) and the respective detector/slit assemblies scan transversely with respect to the incident charged particle beam (Fig. 5 note armature 68) as recited in claims 1-22, 24, and 25.
- 3) A method and device having a controlling means comprising a computer which receives the detected intensity signal from the Faraday detectors and uses these signals to modify a beam distribution to maintain scan uniformity in an implantation process (Col. 8 Lines 10-68) as recited in claims 15 and 18.
- 4) A device and method for determining a direction or parallelism of an ion beam where a portion of the beam is blocked and a "shadow" is formed in the beam downstream of the beam modifying means. Smick et al. calls this shadow "dark current" and uses a fast sampling A/D converter to measure an integrator output during these periods to determine an instrument offset and create a corrected output to account for the "shadow" created during beam sampling by the Faraday detector as it passes though the ion beam as recited in claim 11.

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### Allowable Subject Matter

Claim 23 is allowed.

The following is an examiner's statement of reasons for allowance:

The prior art of Smick et al. teaches a device and method for determining the parallelism and uniformity of a scanned ion beam in an ion implantation device comprising two Faraday detectors. Claim 23 recites a third detector to determine the distribution of the ion beam in three dimensions. While the detectors of Smick et al. scan and determine the distribution of the ion beam, there is no teaching or suggestion in Smick et al. towards the determination of the beam profile in three dimensions or the use of three detectors to accomplish this goal.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

#### Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any Application/Control Number: 09/588,419

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extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later

than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to David A Vanore whose telephone number is 703-306-

0246. The examiner can normally be reached on M-F 7:30-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, John Lee can be reached on 703-308-4116. The fax phone numbers for

the organization where this application or proceeding is assigned are 703-872-9318 for

regular communications and 703-872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is 703-308-

0956.

dav

April 22, 2003

JOHN R. CEE

UPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 2800